# 3.3V TTL/CMOS to Differential PECL Translator

The MC10EPT20 is a 3.3 V TTL/CMOS to differential PECL translator. Because PECL (Positive ECL) levels are used, only +3.3 V and ground are required. The small outline 8–lead SOIC package and the single gate of the EPT20 makes it ideal for those applications where space, performance, and low power are at a premium.

The 100 Series contains temperature compensation.

- 390 ps Typical Propagation Delay
- Maximum Frequency > 1 Ghz Typical
- Differential 3.3 V PECL Outputs
- PNP TTL Inputs for Minimal Loading
- V<sub>CC</sub> Range of 3.0V to 3.6V
- ESD Protection: >1.5 KV HBM, >200 V MM, >2 KV CDM
- Q Output will default HIGH with inputs open
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity Level 1, Indefinite Time Out of Drypack.
   For Additional Information, See Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count = 150 devices

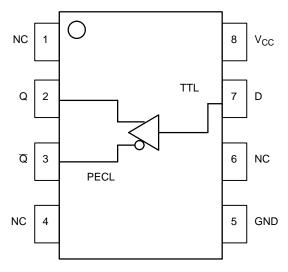


Figure 1. 8-Lead Pinout (Top View) and Logic Diagram
PIN DESCRIPTION

PIN	FUNCTION
$Q, \overline{Q}$	Differential PECL Outputs
D	TTL Input
V <sub>CC</sub>	Positive Supply
GND	Ground
NC	No Connect



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# MARKING DIAGRAMS\*



SO-8 D SUFFIX CASE 751







TSSOP-8 DT SUFFIX CASE 948R



8 A A A A A ALYW

 $\begin{array}{ll} H = MC10 & L = Wafer Lot \\ K = MC100 & Y = Year \\ A = Assembly Location & W = Work Week \\ \end{array}$ 

#### ORDERING INFORMATION

ONDERNING INI ORMATION									
Device	Package	Shipping							
MC10EPT20D	SO-8	98 Units/Rail							
MC10EPT20DR2	SO-8	2500 Tape & Reel							
MC100EPT20D	SO-8	98 Units/Rail							
MC100EPT20DR2	SO-8	2500 Tape & Reel							
MC10EPT20DT	TSSOP-8	98 Units/Rail							
MC10EPT20DTR2	TSSOP-8	2500 Tape & Reel							
MC100EPT20DT	TSSOP-8	98 Units/Rail							
MC100EPT20DTR2	TSSOP-8	2500 Tape & Reel							

### MAXIMUM RATINGS (Note 1.)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V <sub>CC</sub>	Power Supply	GND = 0 V		6	V
VI	Input Voltage	GND = 0 V	$V_{I} \leq V_{CC}$	6	٧
l <sub>out</sub>	Output Current	Continuous Surge		50 100	mA mA
TA	Operating Temperature Range			-40 to +85	°C
T <sub>stg</sub>	Storage Temperature Range			-65 to +150	°C
$\theta_{JA}$	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	8 SOIC 8 SOIC	190 130	°C/W
$\theta_{JC}$	Thermal Resistance (Junction to Case)	std bd	8 SOIC	41 to 44	°C/W
$\theta_{\sf JA}$	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	8 TSSOP 8 TSSOP	185 140	°C/W
$\theta_{JC}$	Thermal Resistance (Junction to Case)	std bd	8 TSSOP	41 to 44	°C/W
T <sub>sol</sub>	Wave Solder	<2 to 3 sec @ 248°C		265	°C

<sup>1.</sup> Maximum Ratings are those values beyond which device damage may occur.

# LVTTL INPUT DC CHARACTERISTICS $V_{CC} = 3.3 \text{ V}$ ; GND = 0 V; $T_A = -40 ^{\circ}\text{C}$ to +85°C

Symbol	Characteristic	Min	Тур	Max	Unit
I <sub>IH</sub>	Input HIGH Current (V <sub>in</sub> = 2.7V)			20	μΑ
I <sub>IHH</sub>	Input HIGH Current MAX (V <sub>in</sub> = 6.0V)			100	μΑ
I <sub>IL</sub>	Input LOW Current (V <sub>in</sub> = 0.5V)			-0.6	mA
V <sub>IK</sub>	Input Clamp Voltage (I <sub>in</sub> = -18mA)			-1.2	V
V <sub>IH</sub>	Input HIGH Voltage	2.0			V
V <sub>IL</sub>	Input LOW Voltage			0.8	V

# 10EPT PECL OUTPUT DC CHARACTERISTICS $V_{CC} = 3.3V$ ; GND = 0V (Note 2.)

		-40°C		25°C			85°C				
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
ICC	Power Supply Current HIGH	18	23	28	18	23	28	19	24	29	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 3.)	2165	2290	2415	2230	2355	2480	2290	2415	2540	mV
V <sub>OL</sub>	Output LOW Voltage (Note 3.)	1365	1490	1615	1430	1555	1680	1490	1615	1740	mV

NOTE: 10EPT circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

- 2. Output parameters vary 1:1 with V<sub>CC</sub>.
- 3. All loading with 50 ohms to  $V_{CC}$ -2.0 volts.

# 100EPT PECL OUTPUT DC CHARACTERISTICS $V_{CC} = 3.3 \text{ V}$ , GND = 0 V (Note 4.)

		-40°C		25°C			85°C				
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>EE</sub>	Power Supply Current	20	25	30	22	27	32	23	28	33	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 5.)	2155	2280	2405	2155	2280	2405	2155	2280	2405	mV
V <sub>OL</sub>	Output LOW Voltage (Note 5.)	1355	1480	1605	1355	1480	1605	1355	1480	1605	mV

NOTE: 100EPT circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

- 4. Output parameters vary 1:1 with V  $_{CC}.$  5. All loading with 50 ohms to V  $_{CC}-2.0$  volts.

AC CHARACTERISTICS  $V_{CC}$  = 3.0 V to 3.6 V; GND = 0 V (Note 6.)

			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f <sub>max</sub>	Maximum Frequency (See Figure 2. F <sub>max</sub> /JITTER)			> 1			> 1			> 1	GHz
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay to Output Differential	280	350	430	300	370	450	320	400	490	ps
t <sub>SKEW</sub>	Device-to-Device Skew (Note 7.)			150			150			170	ps
t <sub>JITTER</sub>	Cycle–to–Cycle Jitter (See Figure 2. F <sub>max</sub> /JITTER)		1	< 2		1	< 2		1	< 2	ps
t <sub>r</sub> t <sub>f</sub>	Output Rise/Fall Times $Q, \overline{Q}$ (20% – 80%)	70	100	170	80	120	180	90	140	190	ps

<sup>6.</sup> Measured using a 750 mV source, 50% duty cycle clock source. All loading with 50 ohms to  $V_{CC}$ -2.0 V. 7. Skew is measured between outputs under identical transitions.

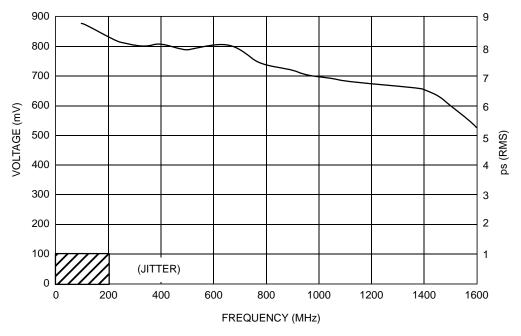


Figure 2. F<sub>max</sub>/Jitter

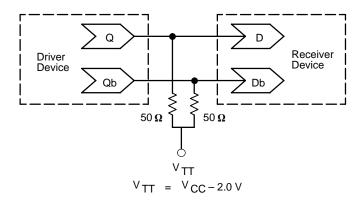


Figure 3. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020 – Termination of ECL Logic Devices.)

# **Resource Reference of Application Notes**

AN1404 – ECLinPS Circuit Performance at Non–Standard V<sub>IH</sub> Levels

AN1405 – ECL Clock Distribution Techniques

AN1406 – Designing with PECL (ECL at +5.0 V)

AN1504 – Metastability and the ECLinPS Family

AN1568 – Interfacing Between LVDS and ECL

AN1650 – Using Wire-OR Ties in ECLinPS Designs

AN1672 – The ECL Translator Guide

AND8001 – Odd Number Counters Design

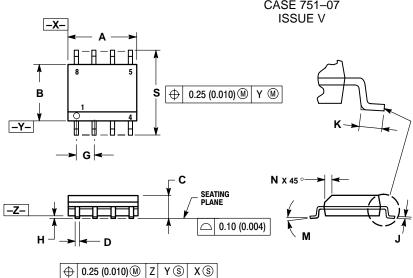
AND8002 - Marking and Date Codes

AND8009 - ECLinPS Plus Spice I/O Model Kit

AND8020 - Termination of ECL Logic Devices

# **PACKAGE DIMENSIONS**

# SO-8 **D SUFFIX** PLASTIC SOIC PACKAGE CASE 751-07

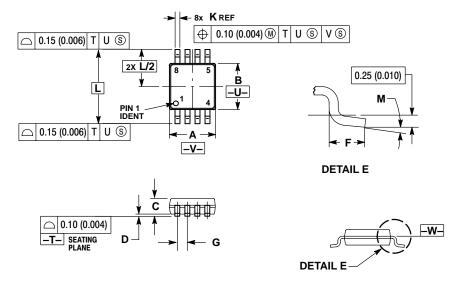


- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE
- 4. MAXIMUM MOLD PHOTHUSION 0.15 (0.006) PER SIDE.
  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INCHES			
DIM	MIN	MAX	MIN	MAX		
Α	4.80	5.00	0.189	0.197		
В	3.80	4.00	0.150	0.157		
С	1.35	1.75	0.053	0.069		
D	0.33	0.51	0.013	0.020		
G	1.27	7 BSC	0.050 BSC			
Н	0.10	0.25	0.004	0.010		
J	0.19	0.25	0.007	0.010		
K	0.40	1.27	0.016	0.050		
M	0 °	8 °	0 °	8 °		
N	0.25	0.50	0.010	0.020		
S	5.80	6.20	0.228	0.244		

# **PACKAGE DIMENSIONS**

# TSSOP-8 **DT SUFFIX** CASE 948R-02 **ISSUE A**



- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: MILLIMETER.

  3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

  4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

  5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

  6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	2.90	3.10	0.114	0.122	
В	2.90	3.10	0.114	0.122	
С	0.80	1.10	0.031	0.043	
D	0.05	0.15	0.002	0.006	
F	0.40	0.70	0.016	0.028	
G	0.65	BSC	0.026	BSC	
Κ	0.25	0.40	0.010	0.016	
٦	4.90	BSC	0.193	BSC	
M	0°	6 °	0°	6°	



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